

ALPIDE

Threshold Scans and Noise Occupancy

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Threshold Scan

Inject well-defined amount of charge in a selected number of pixels

→ Then read out hits and repeat

- Injections are performed multiple times per pixel
- Use only a representative fraction of the Chip (~1-5%)

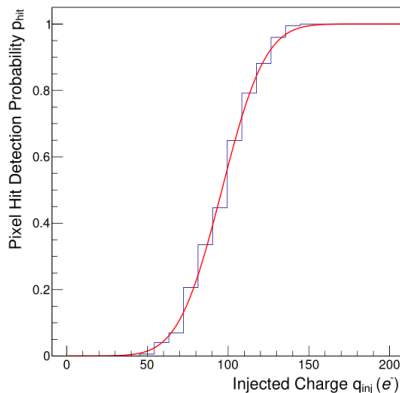
Parameters used:

- PIXPERREGION 1
 - NMASKSTAGES 164
- } Corresponds to $32 \cdot 164 = 5248$ Pixels (1% of the chip)

Threshold Scan

For each charge point on the x-axis, perform 50 Injections, then plot hit probability. (S-Curve scan)

Example:



$$p_{Hit}(q_{inj}) = \frac{1}{2} \left(1 + \text{Erf} \left[\frac{q_{inj} - \mu}{\sqrt{2}\sigma} \right] \right)$$

← Corresponds to a threshold value of roughly $100 e^-$

Definition of Threshold:

The Threshold is the minimum amount of charge to be deposited inside the sensitive region of the chip to create a sufficiently strong signal in order for the readout electronics to register an event

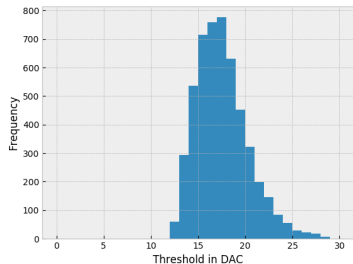
On ALPIDE: Threshold is defined mainly by two parameters: VCASN and ITHR. While increasing ITHR increases the Threshold, augmenting VCASN decreases it.

Threshold Scan

After Scan has completed:

Distribution of Thresholds

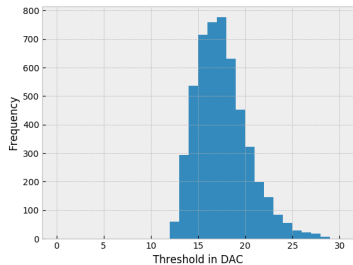
- Extract mean of all pixels



The Plot shows Thresholds of pixels in DAC, where one DAC value corresponds to 10 electrons, i.e. most pixels will register a hit, if the charge injected is higher than 150 electrons

Threshold Scan

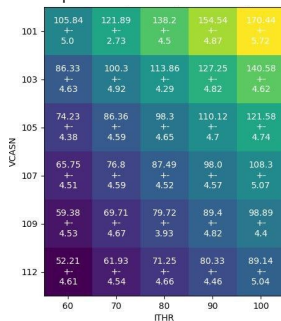
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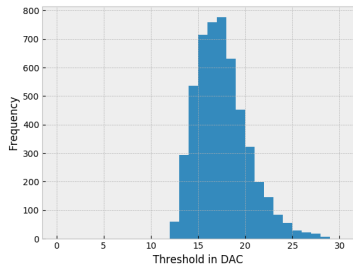
- Extract mean of all pixels
- Repeat with different settings and compare

Charge Threshold for different configurations of the main parameters VCASN and ITHR



Threshold Scan

After Scan has completed:
Distribution of Thresholds



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- Extract mean of all pixels
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Charge Threshold for different configurations of the main parameters VCASN and ITHR



For cosmic muons at 50 GeV: Energy Deposit ~ 0.0286 MeV
7900 e-h-pairs

Noiseoccupancy Scan

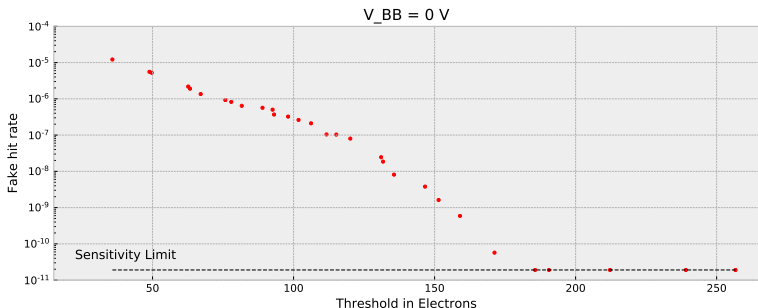
Trigger the whole pixel matrix (!) without any input of charge, and return the number of hits.

- If Threshold is low enough for electronic noise to produce a hit, measurements taken will be affected by a fake hit rate.

Noiseoccupancy Scan

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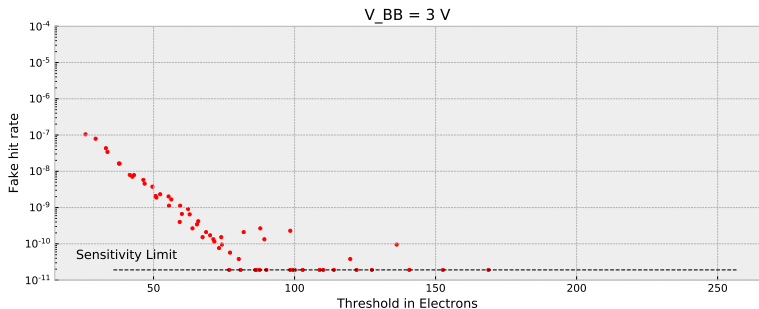
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Noiseoccupancy Scan

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- If Threshold is low enough for electronic noise to produce a hit, measurements taken will be affected by a fake hit rate.



Enlarging the depletion zone by applying a Back-Bias voltage, will have a significant effect on Noise, as is typical for semiconductor detectors

Progress on Cosmics

● Event Plotting

- ▶ Trying to create nice Looking (correctly scaled) 3D- Plots of cosmic tracks
- ▶ Writing an Event organizer for the huge amount of measurements performed

● Track analysis

- ▶ Fitting lines to cosmics to determine valid and invalid tracks

● Plane Alignment

- ▶ Using Tracks to align the Telescope based on cosmic data
- ▶ Comparing results to Testbeam Data from 2019 and 2020
- ▶ Investigating differences in alignment after Transport

